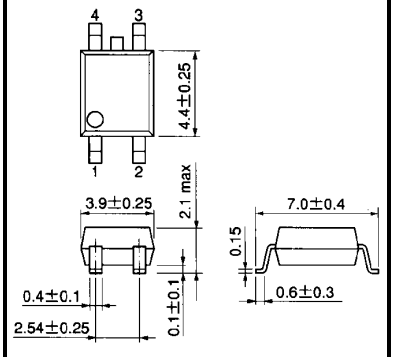
TOSHIBA PHOTOCOUPLER PHOTO RELAY

TLP3113

MEASUREMENT INSTRUMENTS
LOGIC IC TESTERS / MEMORY TESTERS
BOARD TESTERS / SCANNERS

Unit: mm



JEDEC	
JEITA	
TOSHIBA	11−5H1

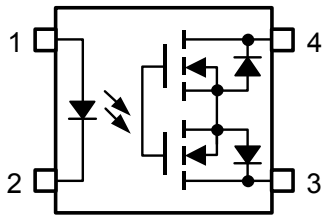
Weight: 0.1 g

The TOSHIBA TLP3113 Mini-flat photorelay is a small-outline photorelay, suitable for surface-mount assembly. The TLP3113 consists of a GaAs infrared-emitting diode optically coupled to a photo-MOS FET and housed in a 4-pin package.
Its characteristics include low OFF-state current and low output pin capacitance, enabling it to be used in high-frequency mearsuring instruments.

FEATURES

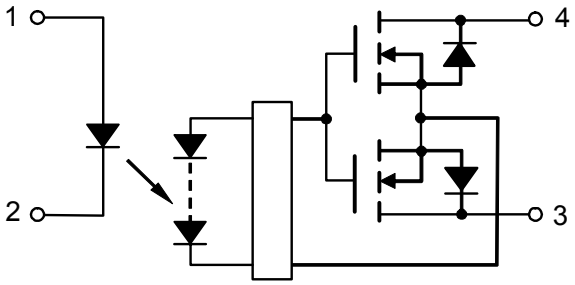
- 4 pin SOP (2.54SOP4) : 2.1 mm high, 2.54 mm pitch
- 1-Form-A
- Peak Off-State Voltage : 40 V (MIN.)
- Trigger LED Current : 4 mA (MAX.)
- On-State Current : 80 mA (MAX.)
- On-State Resistance : 35 Ω (MAX.), 25 Ω (TYP.)
- Output Capacitance : 1.4 pF (MAX.), 0.6 pF (TYP.)
- Isolation Voltage : 1500 Vrms (MIN.)

PIN CONFIGURATION (TOP VIEW)



1 : ANODE
2 : CATHODE
3 : DRAIN
4 : DRAIN

SCHEMATIC



MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
LED	Forward Current	I_F	50	mA
	Forward Current Derating (Ta ≧ 25°C)	ΔI_F/°C	−0.5	mA/°C
	Reverse Voltage	V_R	5	V
	Junction Temperature	T_j	125	°C
DETECTOR	Off-State Output Terminal Voltage	V_{OFF}	40	V
	On-State Current	I_{ON}	80	mA
	On-State Current Derating (Ta ≧ 25°C)	ΔI_{ON}/°C	−0.8	mA/°C
	Junction Temperature	T_j	125	°C
Storage Temperature Range		T_{stg}	−40~125	°C
Operating Temperature Range		T_{opr}	−20~85	°C
Lead Soldering Temperature (10 s)		T_{sol}	260	°C
Isolation Voltage (AC, 1 minute, R.H. ≦ 60%) (NOTE1)		BV_S	1500	Vrms

(NOTE1) : Device considered a two-terminal device : Pins 1 and, 2 shorted together, and pins 3 and 4 shorted together.

CAUTION

This device is sensitive to electrostatic discharge. When using this device, please ensure that all tools and equipment are earthed.

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V_{DD}	—	—	32	V
Forward Current	I_F	10	—	30	mA
On-State Current	I_{ON}	—	—	80	mA
Operating Temperature	T_{opr}	25	—	60	°C

INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	V_F	I_F = 10 mA	1.0	1.15	1.3	V
	Reverse Current	I_R	V_R = 5 V	—	—	10	μA
	Capacitance	C_T	V = 0, f = 1 MHz	—	15	—	pF
DETECTOR	Off-State Current	I_{OFF}	V_{OFF} = 30 V, Ta = 50°C	—	—	1000	pA
	Capacitance	C_{OFF}	V = 0, f = 100 MHz, t < 1 s	—	0.6	1.4	pF

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	I_{FT}	I_{ON} = 80 mA	—	—	4	mA
Return LED Current	I_{FC}	I_{OFF} = 10 μA	0.2	0.75	—	mA
On-State Resistance	R_{ON}	I_{ON} = 80 mA, I_F = 5 mA, t < 1 s	—	25	35	Ω

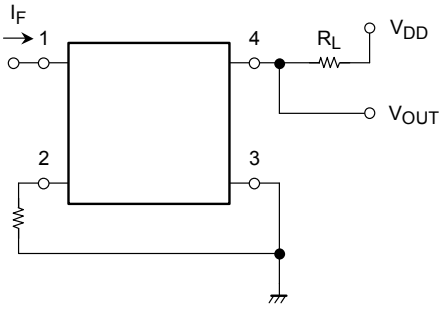
ISOLATION CHARACTERISTICS (Ta = 25°C)

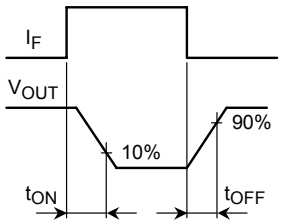
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance Input to Output	C_S	V_S = 0 V, f = 1 MHz	—	0.8	—	pF
Isolation Resistance	R_S	V_S = 500 V, R.H. ≦ 60%	5×10^{10}	10^{14}	—	Ω
Isolation Voltage	BV_S	AC, 1 minute	1500	—	—	Vrms
		AC, 1 second (in oil)	—	3000	—	
		DC, 1 minute (in oil)	—	3000	—	Vdc

SWITCHING CHARACTERISTICS (Ta = 25°C)

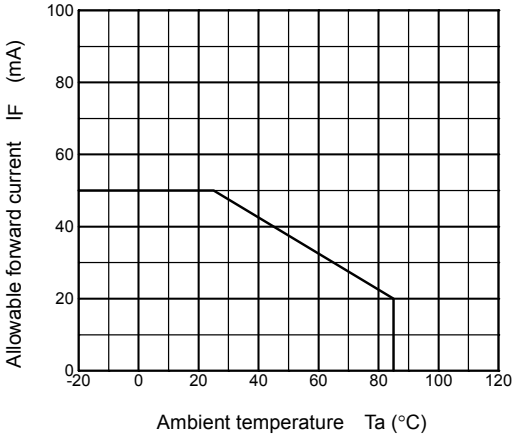
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Turn-on Time	t_{ON}	R_L = 200 Ω (NOTE 2) V_{DD} = 10 V, I_F = 10 mA	—	—	500	μs
Turn-off Time	t_{OFF}		—	—	500	

(NOTE 2) : SWITCHING TIME TEST CIRCUIT

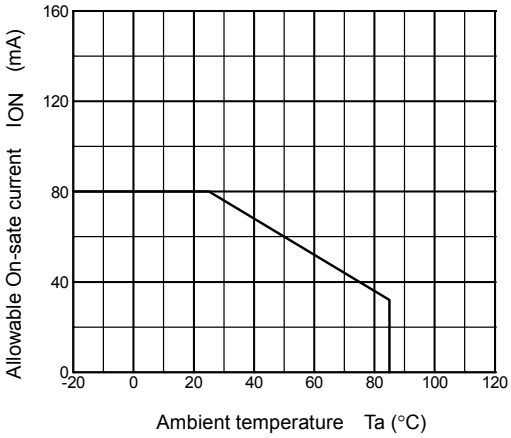




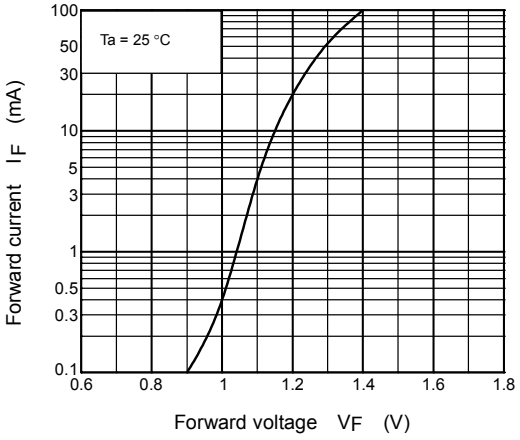
$I_F - Ta$



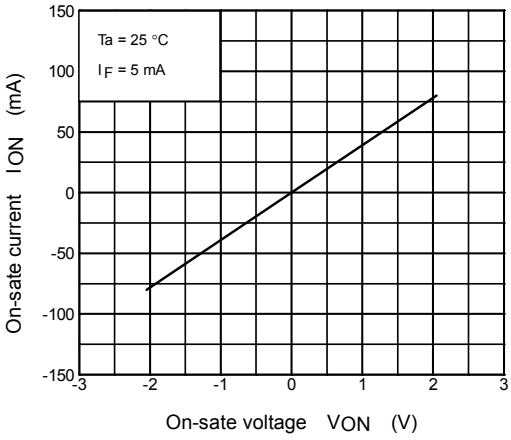
$I_{ON} - Ta$



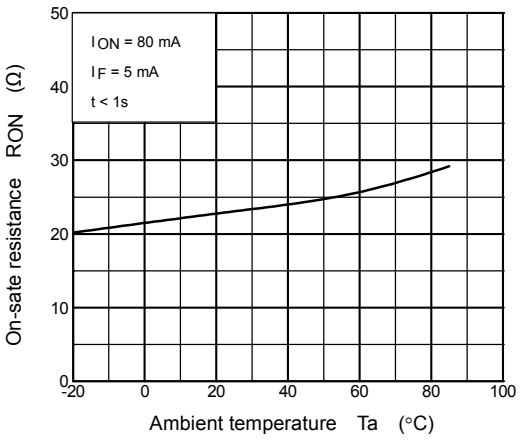
$I_F - V_F$



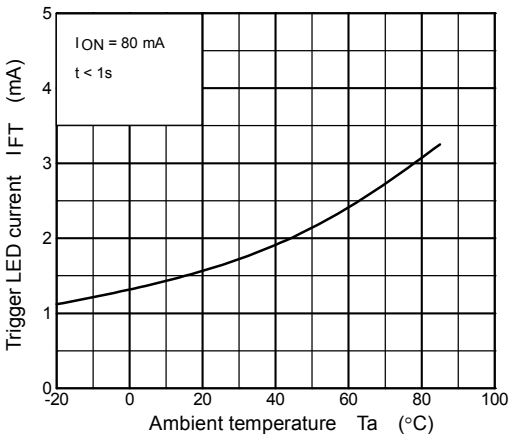
$I_{ON} - V_{ON}$



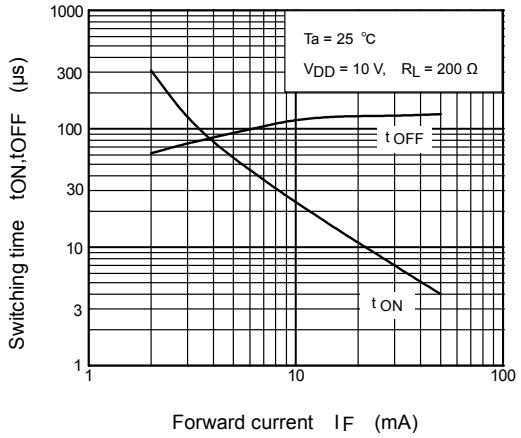
$R_{ON} - Ta$



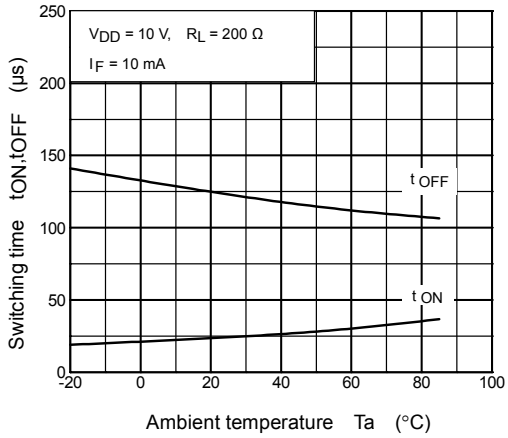
$I_{FT} - Ta$



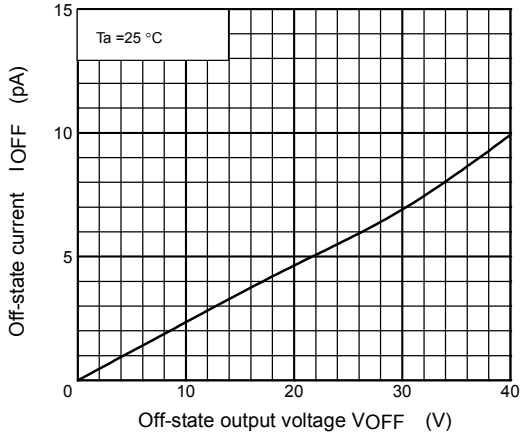
tON,tOFF – IF



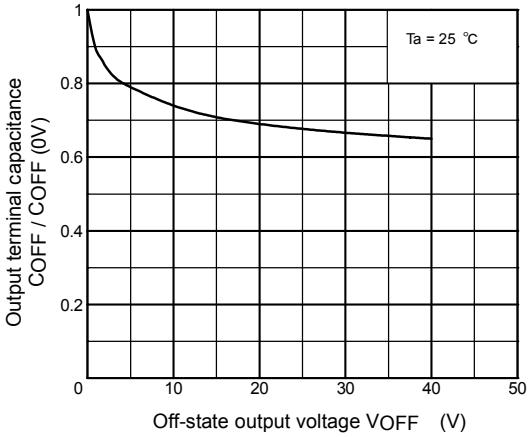
tON,tOFF – Ta



IOFF – VOFF



COFF – VOFF



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